2N4427

SILICON NPN RF TRANSISTOR



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DESCRIPTION:

The CENTRAL SEMICONDUCTOR 2N4427 is a silicon NPN epitaxial planar RF transistor mounted in a hermetically sealed package designed for high frequency amplifier applications.

MARKING: FULL PART NUMBER



MAXIMUM RATINGS: (T_A=25°C unless otherwise noted)

	SYMBOL		UNITS
Collector-Base Voltage	V_{CBO}	40	V
Collector-Emitter Voltage	VCEO	20	V
Emitter-Base Voltage	V_{EBO}	2.0	V
Continuous Collector Current	I_{C}	400	mA
Continuous Base Current	Ι _Β	400	mA
Power Dissipation	P_{D}	1.0	W
Power Dissipation (T _C =25°C)	P_{D}	3.5	W
Operating and Storage Junction Temperature	T _J , T _{sta}	-65 to +200	°C

 $\textbf{ELECTRICAL CHARACTERISTICS:} \ (T_{\mbox{\scriptsize A}} = 25^{\circ}\mbox{C unless otherwise noted})$

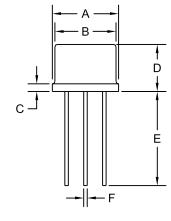
SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
ICEV	V_{CE} =40V, V_{BE} =1.5V		100	μΑ
ICEV	V_{CE} =12V, V_{BE} =1.5V, T_{C} =150°C		5.0	mA
ICEO	V _{CE} =12V		20	μΑ
I _{EBO}	V _{EB} =2.0V		100	μΑ
BV CER	I_C =5.0mA, R_{BE} =10 Ω	40		V
BVCEO	I _C =5.0mA	20		V
V _{CE(SAT)}	I _C =100mA, I _B =20mA		0.5	V
h _{FE}	V_{CE} =5.0V, I_{C} =100mA	10	200	
hFE	V_{CE} =5.0V, I_{C} =360mA	5.0		
f _T	V_{CE} =15V, I_{C} =50mA, f=200MHz	500		MHz
C_{ob}	V_{CB} =12V, I_E =0, f=1.0MHz		4.0	pF
G _{pe}	V_{CC} =12V, P_{in} =100mW, f=175MHz	10		dB
η	V_{CC} =12V, P_{out} =1.0W, f=175MHz	50		%
P _{in}	V _{CC} =12V, P _{out} =1.0W, f=175MHz		100	mW

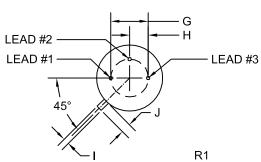
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TO-39 CASE - MECHANICAL OUTLINE





DIMENSIONS						
	INCHES		MILLIMETERS			
SYMBOL	MIN	MAX	MIN	MAX		
A (DIA)	0.335	0.370	8.51	9.40		
B (DIA)	0.315	0.335	8.00	8.51		
С	-	0.040	-	1.02		
D	0.240	0.260	6.10	6.60		
E	0.500	-	12.70	-		
F (DIA)	0.016	0.021	0.41	0.53		
G (DIA)	0.200		5.08			
Н	0.100		2.54			
	0.028	0.034	0.71	0.86		
J	0.029	0.045	0.74	1.14		

TO-39 (REV: R1)

LEAD CODE:

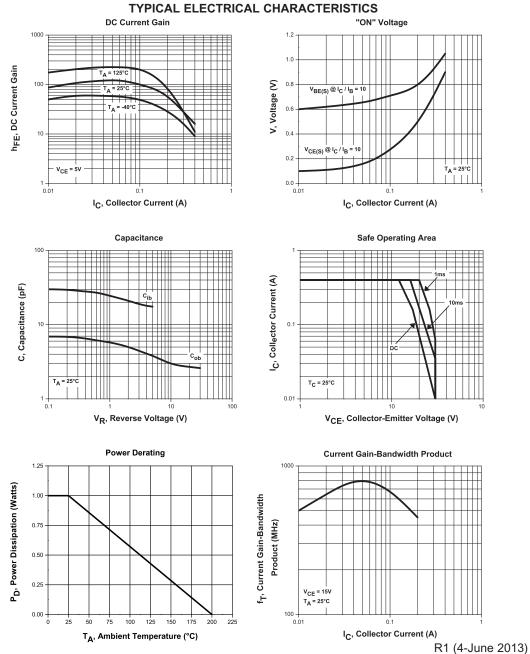
- 1) Emitter
- 2) Base
- 3) Collector

MARKING: FULL PART NUMBER

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OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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